

SONY

CXG1010N

Power Amplifier for PHS

Description

The CXG1010N is a power amplifier for PHS. This IC is designed using the Sony's GaAs J-FET process and operates at a single power supply.

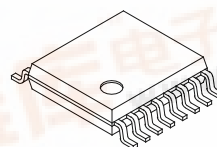
Features

- High output power 21.5 dBm
- Positive power supply drive $V_{DD}=3.4$ V
- Low current consumption 200 mA
- High gain 40 dB Typ.
- Low distortion (ACP) -59 dBc Typ.
- Small mold package 16-pin SSOP

Structure

GaAs J-FET MMIC

16 pin SSOP (Plastic)

Absolute Maximum Ratings ($T_a=25^\circ\text{C}$)

- Supply voltage V_{DD} 6 V
- Voltage between gate and source V_{GS0} 1.5 V
- Drain current I_{DD} 500 mA
- Power dissipation P_D 3 W
- Channel temperature T_{ch} 175 $^\circ\text{C}$
- Operating temperature T_{op} -35 to +85 $^\circ\text{C}$
- Storage temperature T_{stg} -65 to +150 $^\circ\text{C}$

Electrical Characteristics

 $V_{DD}=3.4$ V, $V_{CTL}=2.0$ V, $f=1.90$ GHz($T_a=25^\circ\text{C}$)

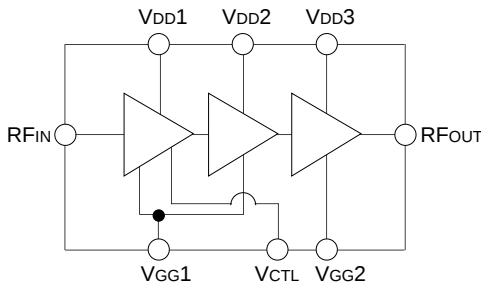
Item	Symbol	Min.	Typ.	Max.	Unit
*1 Current consumption	I_{DD}		200		mA
*1 Gate voltage adjustment value	V_{GG2}	0	0.5	1.0	V
Input VSWR	$VSWR_{IN}$		1.5	2.0	—
Output power (for -15.5 dBm input)	P_{OUT}	21.5			dBm
*2 Power gain	G_P	37	40	43	dB
*2 Gain control	G_{CTL}		20		dB
*2 Average leak power level (600 kHz $\pm$ 100 kHz)	$P_{LEAK600}$		-59	-54	dBc
*2 Average leak power level (900 kHz $\pm$ 100 kHz)	$P_{LEAK900}$		-65	-59	dBc

*1 This value is adjusted by V_{GG1} and V_{GG2} set with Sony's recommended current adjustment method when 21.5 dBm is output. In this time, the voltage ratio of V_{GG1} and V_{GG2} should match to the voltage ratio generated by the resistance of the recommended gate bias circuit.

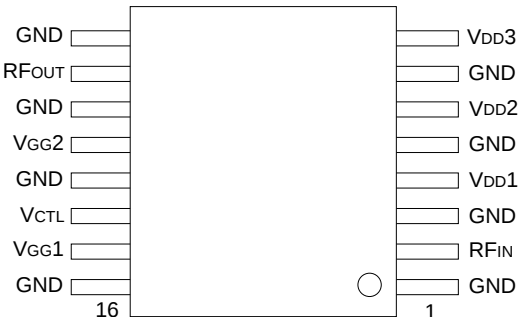
*2 When 21.5 dBm is output.

*3 $G_{CTL}=G_P (V_{CTL} 2.0 \text{ V}) - G_P (V_{CTL} 0 \text{ V})$

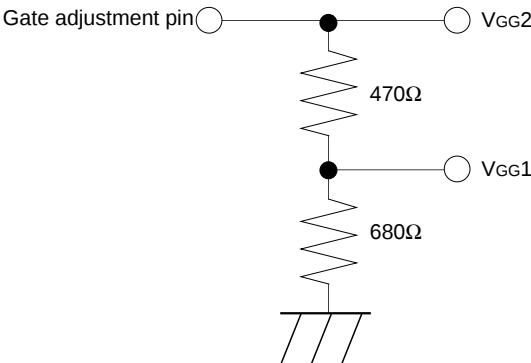
Block Diagram



Pin Configuration

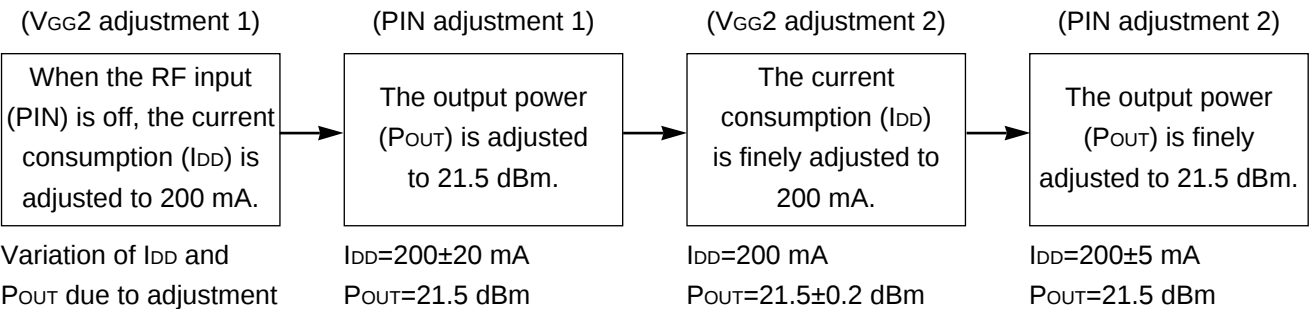


Gate adjustment pin

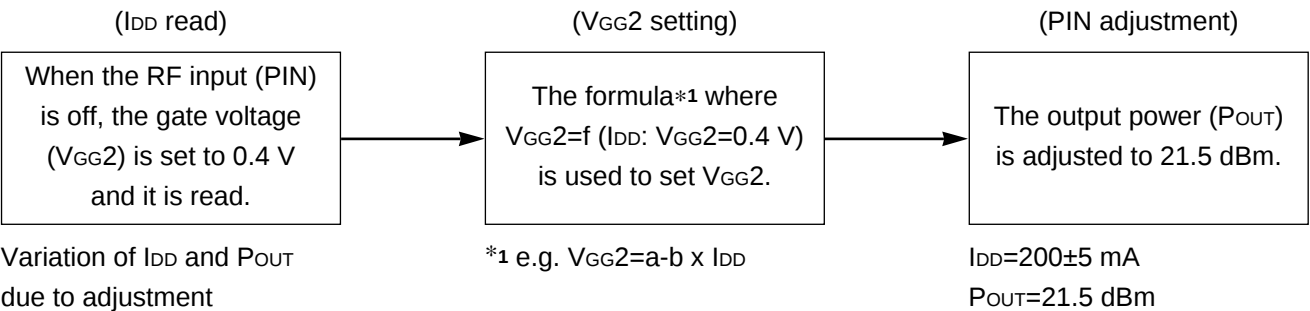


Recommended Current Adjustment Method

(1) VGG2/PIN separate adjustment



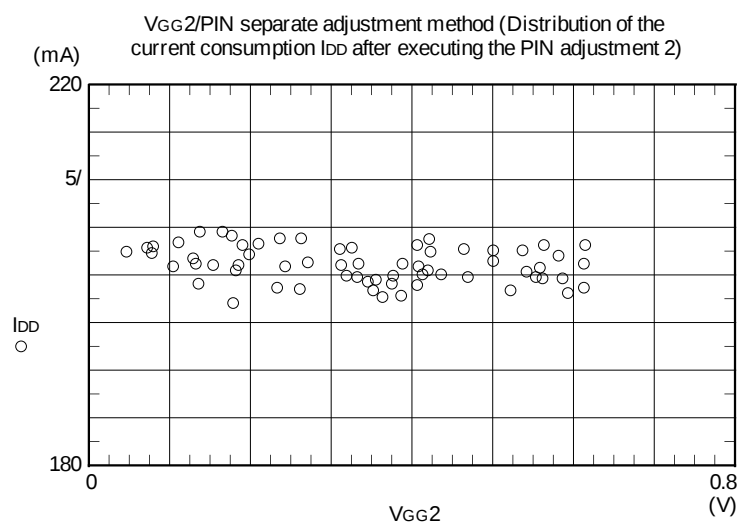
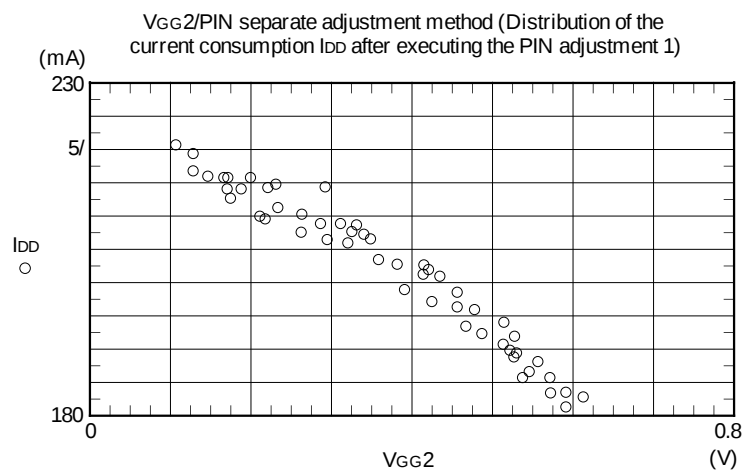
(2) Simple adjustment



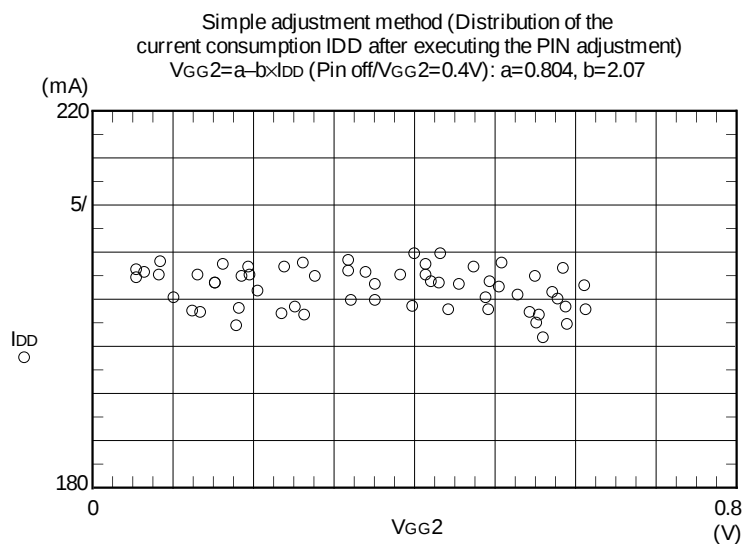
Current Consumption Variation with Recommended Current Adjustment Method

(For $P_{OUT}=21.5$ dBm output)

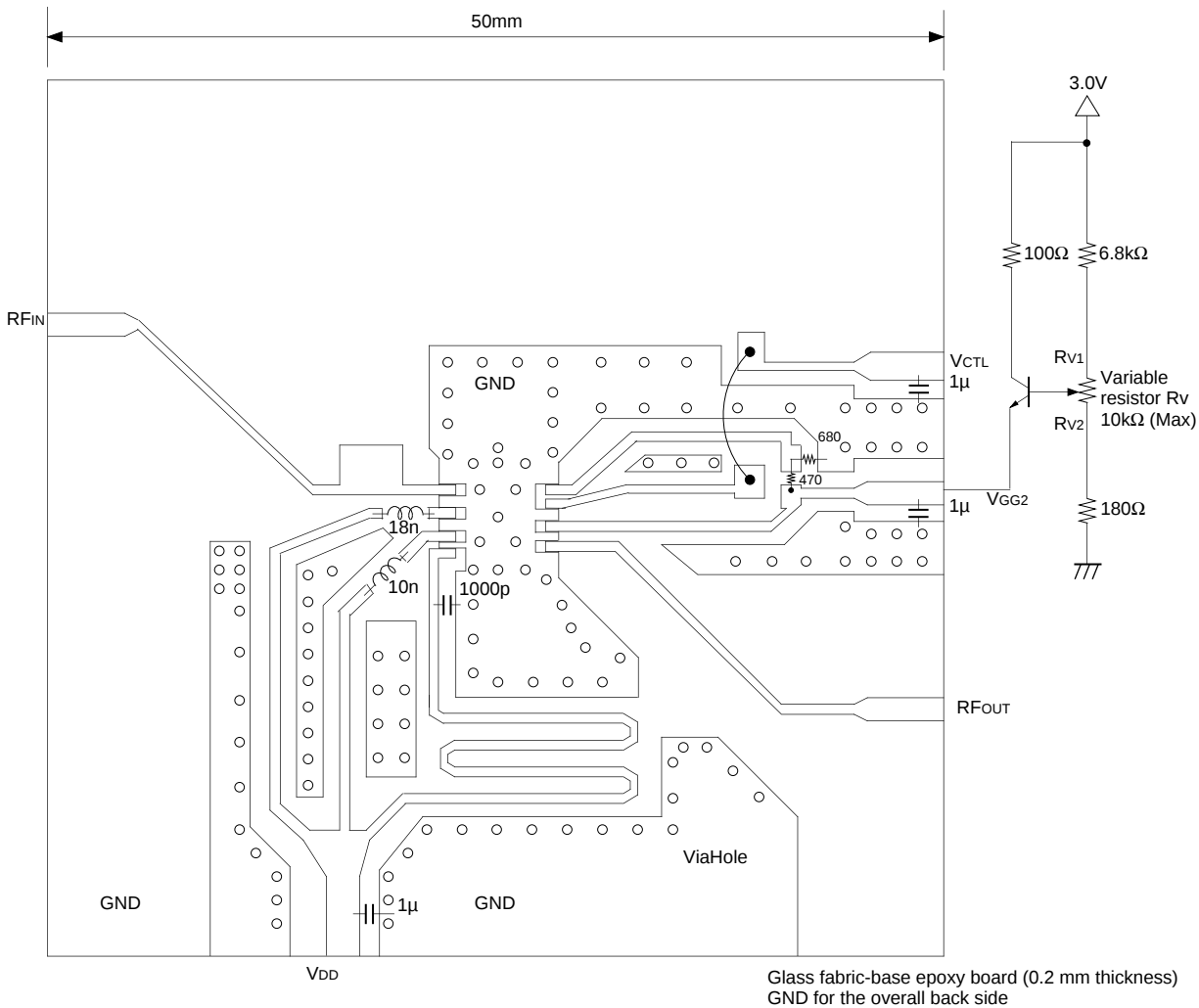
(1) Separate adjustment



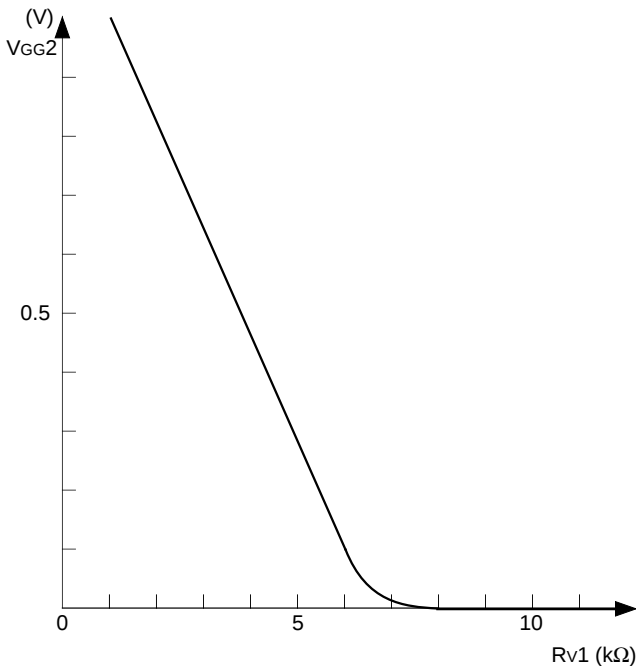
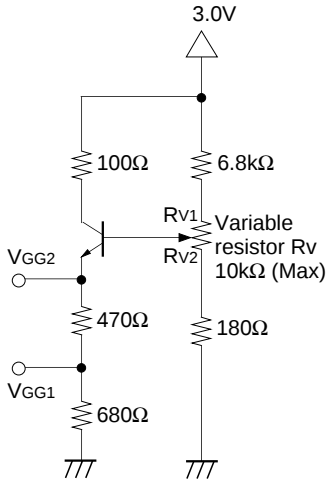
(2) Simple adjustment



Recommended Evaluation Circuit

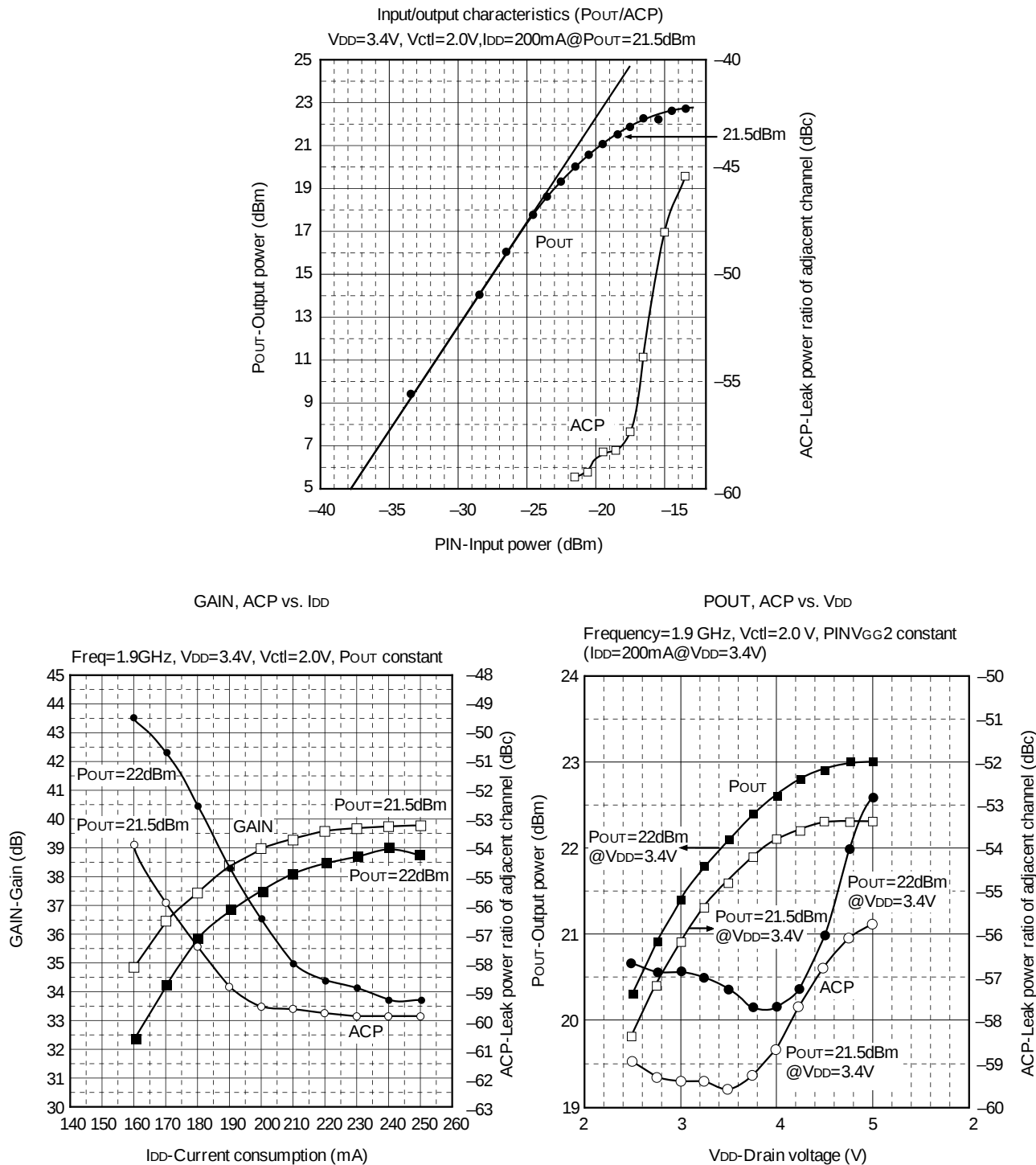


Recommended Gate Bias Circuit and Circuit Characteristics



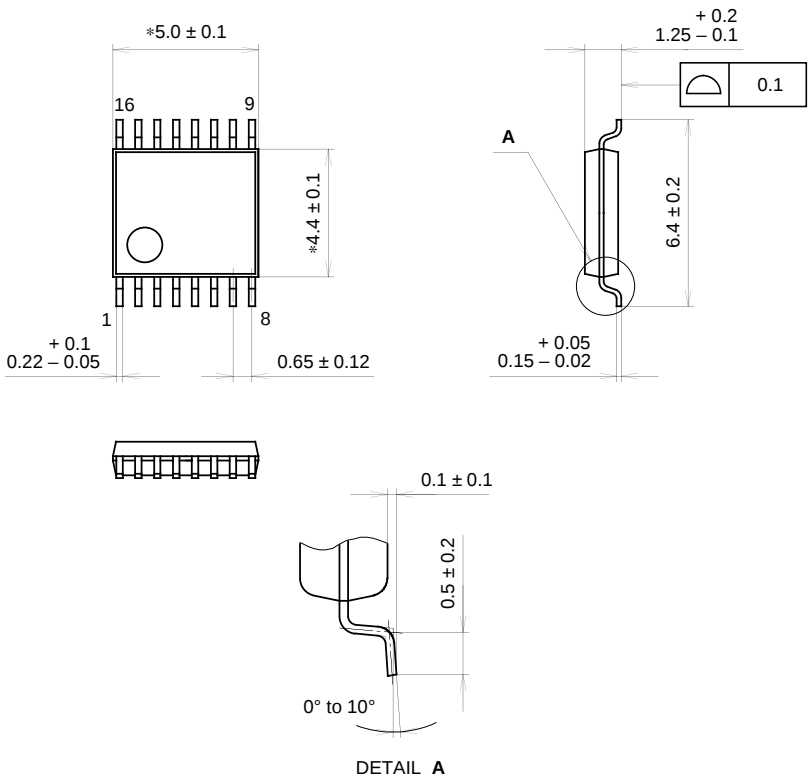
Application circuits shown are typical examples illustrating the operation of the devices. Sony cannot assume responsibility for any problems arising out of the use of these circuits or for any infringement of third party and other right due to same.

Example of Representative Characteristics (Ta=25 °C)



Package Outline Unit : mm

16PIN SSOP (PLASTIC)



NOTE: Dimension "*" does not include mold protrusion.

PACKAGE STRUCTURE

SONY CODE	SSOP-16P-L01	PACKAGE MATERIAL	EPOXY RESIN
EIAJ CODE	SSOP016-P-0044	LEAD TREATMENT	SOLDER / PALLADIUM PLATING
JEDEC CODE		LEAD MATERIAL	COPPER / 42 ALLOY
		PACKAGE WEIGHT	0.1g